

NCE P-Channel Enhancement Mode Power MOSFET

Description

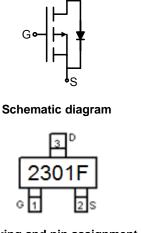
The NCE2301F uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.

General Features

- $V_{DS} = -20V, I_D = -2 A$ $R_{DS(ON)} < 150m\Omega @ V_{GS} = -2.5V$ $R_{DS(ON)} < 120m\Omega @ V_{GS} = -4.5V$
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

Application

- PWM applications
- Load switch



Marking and pin assignment



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2301F	NCE2301F	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-20	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	ID	-2.0	A
Drain Current -Pulsed (Note 1)	I _{DM}	-10	A
Maximum Power Dissipation	PD	0.7	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	178	°C /W
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-20		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-20V, V_{GS} =0V	-	-	-1	μA





NCE2301F

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	·······································		•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.4	-0.7	-1	V
		V _{GS} =-4.5V, I _D =-2 A	-	88	120	mΩ
Drain-Source On-State Resistance	Rds(on)	V _{GS} =-2.5V, I _D =-1.8A	-	120	150	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-2A	4	-	-	S
Dynamic Characteristics (Note4)						1
Input Capacitance	C _{lss}		-	285	-	PF
Output Capacitance	Coss	V _{DS} =-10V,V _{GS} =0V,	-	58	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	32	-	PF
Switching Characteristics (Note 4)	I					
Turn-on Delay Time	t _{d(on)}		-	9.8	-	nS
Turn-on Rise Time	tr	V _{DD} =-10V, R _L =5Ω V _{GS} =-4.5V,R _{GEN} =3Ω	-	4.9	-	nS
Turn-Off Delay Time	t _{d(off)}		-	20.5	-	nS
Turn-Off Fall Time	tr		-	7	-	nS
Total Gate Charge	Qg	V _{DS} =-10V,I _D =-2A,	-	2.9	-	nC
Gate-Source Charge	Q _{gs}		-	0.45	-	nC
Gate-Drain Charge	Q _{gd}	V_{GS} =-4.5V	-	0.75	-	nC
Drain-Source Diode Characteristics						1
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-2A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-2.0	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



NCE2301F



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Typical Electrical and Thermal Characteristics

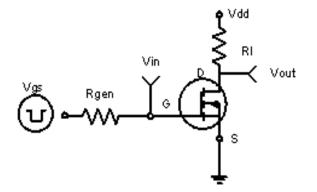
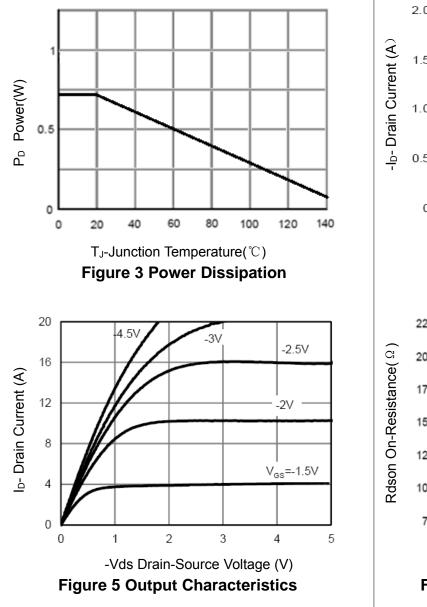


Figure 1:Switching Test Circuit



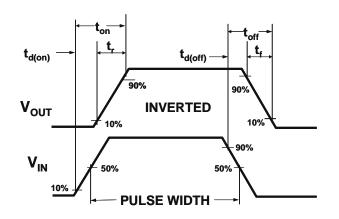
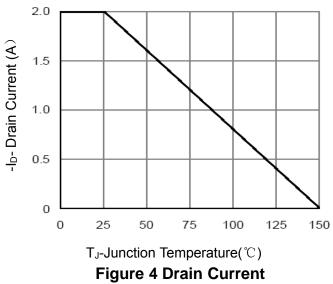
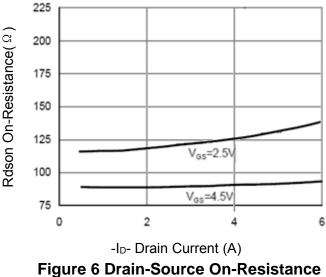


Figure 2:Switching Waveforms

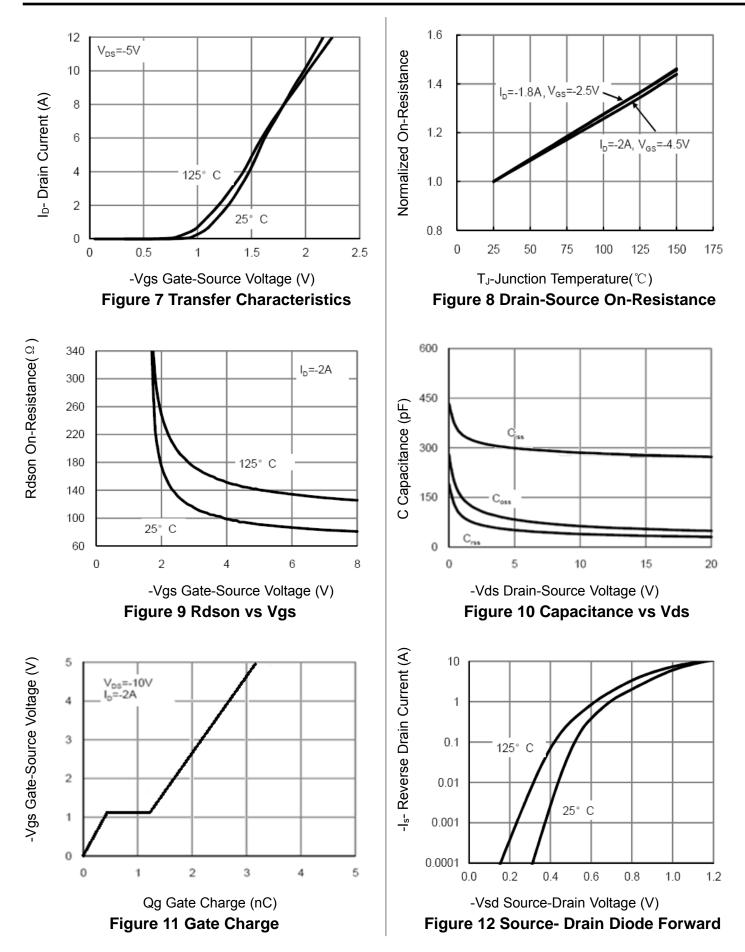






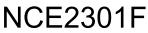
Pb Free Product

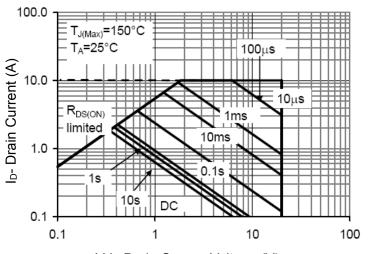
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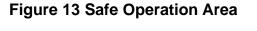








Vds Drain-Source Voltage (V)



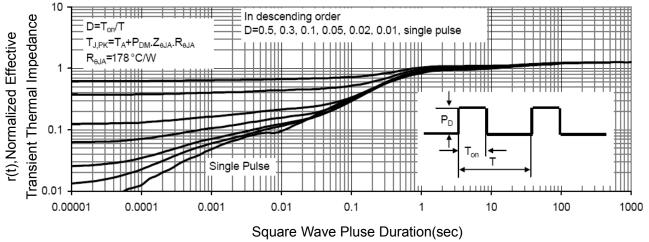
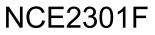
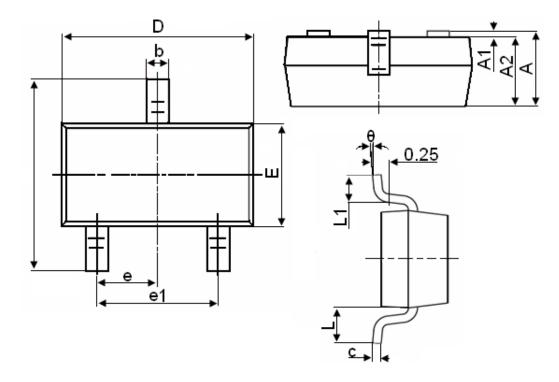


Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



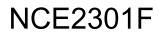
Symbol	Dimensions in Millimeters			
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е	0.950TYP			
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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